

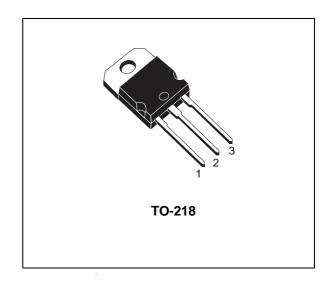
## COMPLEMENTARY SILICON POWER TRANSISTORS

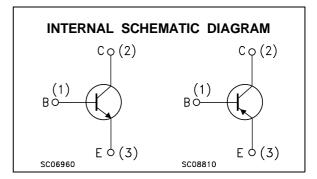
- STMicroelectronics PREFERRED SALESTYPES
- COMPLEMENTARY PNP NPN DEVICES

#### **DESCRIPTION**

The TIP3055 is a silicon Epitaxial-Base Planar NPN transistor mountend in TO-218 plastic package. It is intented for power switching circuits, series and shunt regulators, output stages and hi-fi amplifiers.

The complementary PNP type is the TIP2955.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit
		PNP	TIP2955	
		NPN	TIP3055	
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)		100	V
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)		60	V
Ic	Collector Current		15	А
Ι <sub>Β</sub>	Base Current		7	Α
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> ≤ 25 °C		90	W
T <sub>stg</sub>	Storage Temperature		-65 to 150	°C
Tj	Max. Operating Junction Temperature		150	°C

For PNP types voltage and current are negative.

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### TIP2955/TIP3055

### THERMAL DATA

R <sub>thj-case</sub> Therm	al Resistance Junction-case	Max	1.4	°C/W	
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## **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25$ $^{\circ}C$ unless otherwise specified)

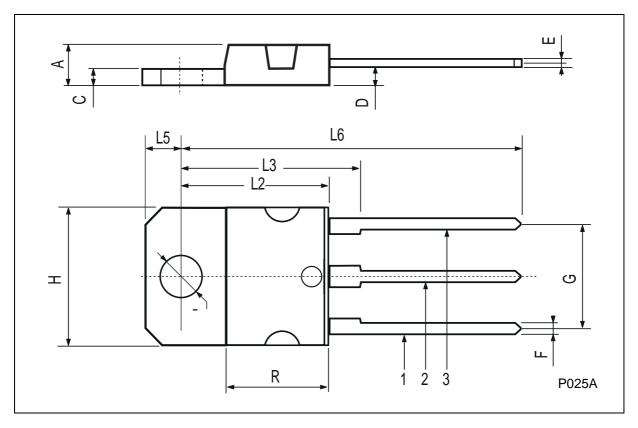
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CEX</sub>	Collector Cut-off Current (V <sub>BE</sub> = -1.5V)	V <sub>CE</sub> = 100 V V <sub>CE</sub> = 100 V T <sub>J</sub> = 150 °C			1 5	mA mA
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 30 V			0.7	mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 7 V			5	mA
V <sub>CEO(sus)*</sub>	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 30 mA	60			V
V <sub>CE(sat)*</sub>	Collector-emitter Saturation Voltage	I <sub>C</sub> = 4 A			1 3	V
V <sub>BE</sub> *	Base-emitter Voltage	$I_C = 4 A$ $V_{CE} = 4 V$			1.8	V
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 4 A	20 5		70	
h <sub>fe</sub>	Small Signal Current Gain	Ic = 1 A V <sub>CE</sub> = 10 V f = 1 KHz	15			
f⊤	Transition-Frequency	$I_C = 0.5 \text{ A}  V_{CE} = 10 \text{ V}  f = 1 \text{ MHz}$	3			MHz
t <sub>on</sub> t <sub>off</sub>	RESISTIVE LOAD Turn-on Time Turn-off Time	$I_{C} = 6 \text{ A}$ $I_{B1} = -I_{B2} = 0.6 \text{ A}$ $V_{BE(off)} = -4 \text{ V}$		0.5 0.9		μs μs

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<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 % For PNP type, voltage and current value are negative.

# TO-218 (SOT-93) MECHANICAL DATA

DIM.	mm		inch			
DIW.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	4.7		4.9	0.185		0.193
С	1.17		1.37	0.046		0.054
D		2.5			0.098	
E	0.5		0.78	0.019		0.030
F	1.1		1.3	0.043		0.051
G	10.8		11.1	0.425		0.437
Н	14.7		15.2	0.578		0.598
L2	-		16.2	_		0.637
L3		18			0.708	
L5	3.95		4.15	0.155		0.163
L6		31			1.220	
R	-		12.2			0.480
Ø	4		4.1	0.157		0.161



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